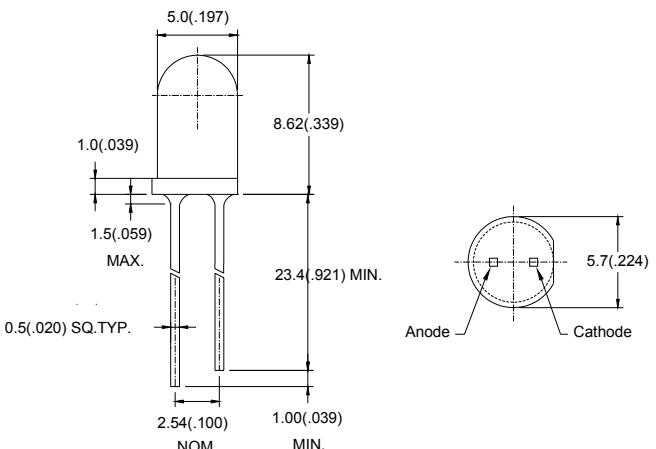


END-LOOK PACKAGE LIGHT EMITTING DIODE

● Features:

1. High radiant power and high radiant intensity.
2. Standard T-1 3/4(5mm)package.
3. Peak wavelength $\lambda_p=850\text{nm}$.
4. Good spectral matching to si-photodetector.
5. Radiant angle: 20°
6. Lens Appearance: Water Clear.
7. This product doesn't contain restriction substance, comply ROHS standard

● Package Dimensions:



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25\text{mm}$ ($0.01''$) unless otherwise specified.
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

● Applications:

1. Remote Control.
2. Automatic Control System.

● Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Power Dissipation	Pd	100	mW
Continuous Forward Current	I _F	100	mA
Peak Forward Current ^{*1}	I _{FP}	1.0	A
Reverse Voltage	V _R	5	V
Operating Temperature	T _{opr}	-45°C ~ 85°C	-
Storage Temperature	T _{stg}	-45°C ~ 100°C	-
Soldering Temperature	T _{sol}	260°C (for 5 seconds)	-

^{*1} Condition for is I_{FP} pulse of 1/10 duty and 0.1 msec width.

- **Optical- Electrical Characteristics (@ $T_A=25^\circ\text{C}$)**

Parameter	Symbol	Test Conditions	Min	TYP	Max	Unit
Radiant Intensity	I_e	$I_F=50\text{mA}$	45.31	128.5	-	mW/sr
Forward Voltage	V_F	$I_F=50\text{mA}$	-	1.5	1.8	V
Reverse Current	I_R	$V_R=5\text{V}$	-	-	10	μA
Peak Wavelength	λ_p	$I_F=20\text{mA}$	-	850	-	nm
Spectral Line Half- Width	$\Delta\lambda$	$I_F=20\text{mA}$	-	50	-	nm
Viewing Angle	$2\theta_{1/2}$	$I_F=20\text{mA}$	-	20	-	deg

- **Typical Optical-Electrical Characteristic Curves**

Fig.1 Spectral Dlstrbution

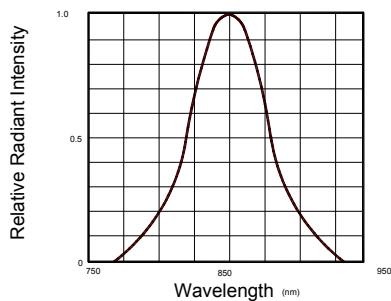


Fig.2 Forward Current Vs
Ambient Temperature

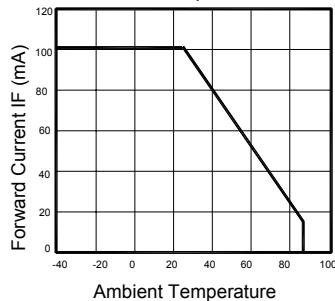


Fig.3 Forward Current Vs

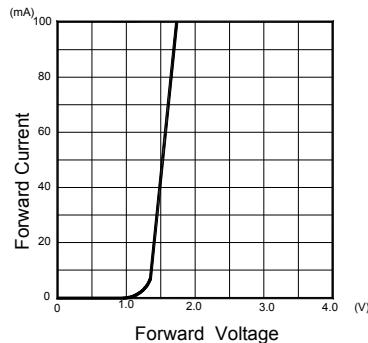


Fig.4 Relative Radiant Intensity
Vs Ambent Tembeb Ature

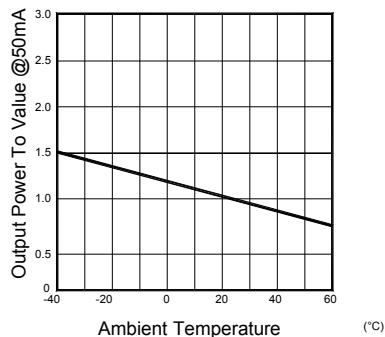


Fig.5 Relative Radiant Intensity
Vs Forward Current

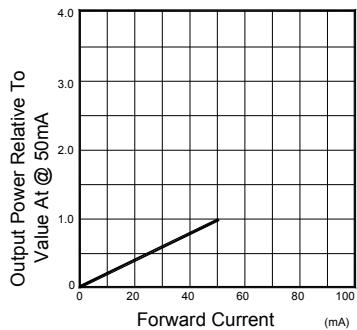
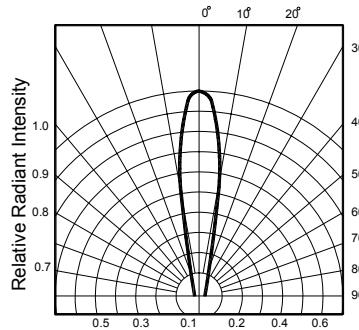
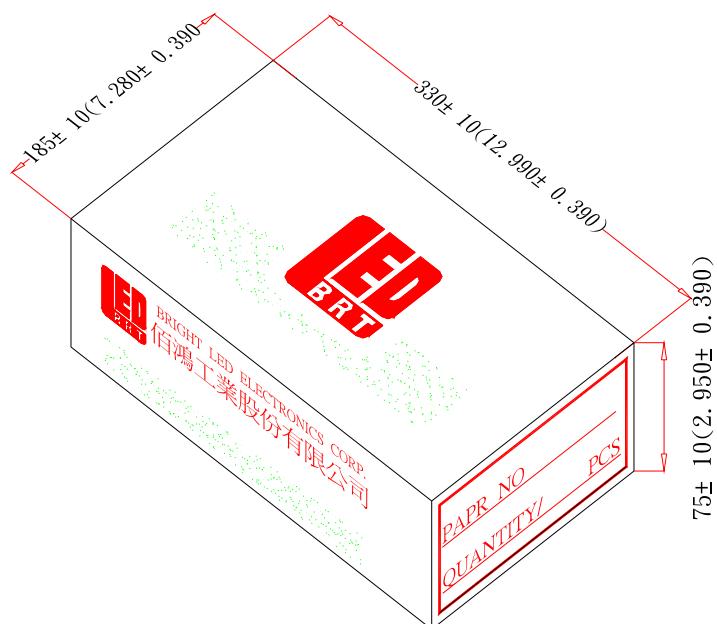


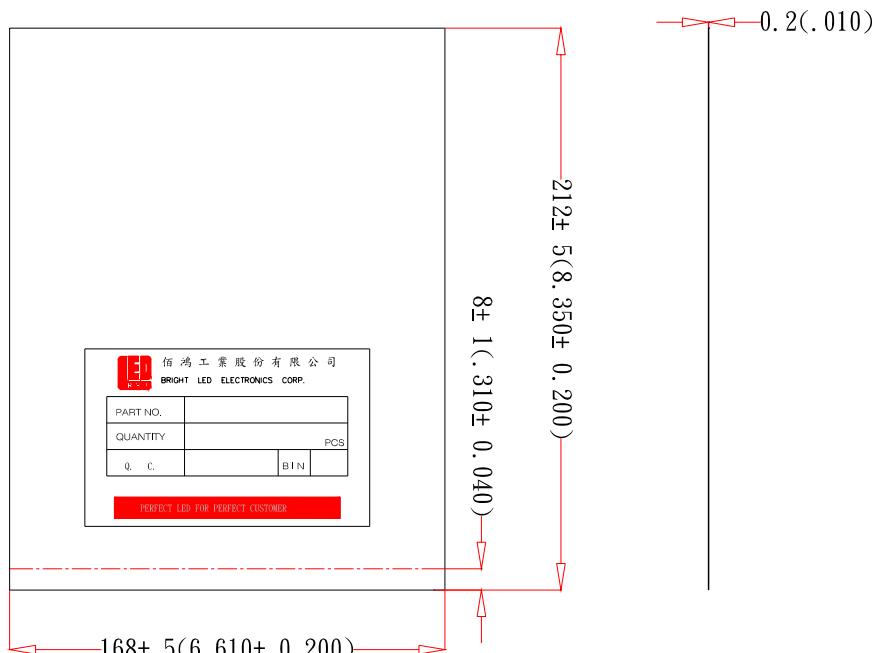
Fig.6 Radiation Diagram



- Tapping and packaging specifications(Units: mm)



- Packaging Bag Dimensions



Notes:

- 1、500pcs per bag, 5Kpcs per box.
- 2、All dimensions are in millimeters(inches).
- 3、Specifications are subject to change without notice.



BRIGHT LED ELECTRONICS CORP.

BIR-BO13J4G

Infrared Emitting Diode Specification

- Commodity: Infrared emitting diode
- Intensity Bin Limits (At 50mA)

BIN CODE	Min.(mW/sr)	Max.(mW/sr)
15	32.36	61.30
16	45.31	85.82
17	63.43	120.15
18	88.80	168.21